

MiniSKiiP[®] 2

Twin 6-pack

SKiiP 24ACC12T4V10

Features

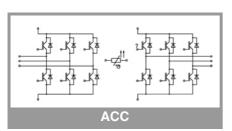
- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for
- electrical connectionsUL recognised: File no. E63532

Typical Applications*

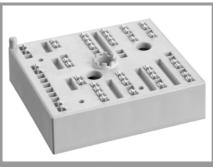
• 4Q inverters

Remarks

- Max. case temperature limited to $T_C=125^{\circ}C$
- Product reliability results valid for $T_j \le 150^{\circ}C$ (recommended $T_{j,op} = -40... + 150^{\circ}C$)
- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage V_{DC}≤800V
- Temperature sensor: no basic insulation to main circuit, signal processing with reference to –DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information



Absolute	e Maximum Ratings	6			
Symbol	Conditions		Values	Unit	
IGBT 1 -	6				
V _{CES}	T _j = 25 °C		1200	V	
lc	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	41	Α	
	T _j = 175 °C	T _s = 70 °C	34	Α	
l _C	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	45	А	
	T _j = 175 °C	T _s = 70 °C	37	Α	
I _{Cnom}			25	А	
I _{CRM}	I _{CRM} = 3 x I _{Cnom}		75	Α	
V_{GES}			-20 20	V	
t _{psc}	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T _j = 150 °C	10	μs	
Tj			-40 175	°C	
IGBT 7 -	12				
V _{CES}	$T_j = 25 \text{ °C}$ $\lambda_{\text{roots}} = 0.8 \text{ W/(mK)}$ $T_s = 25 \text{ °C}$		1200	V	
lc	$\lambda_{paste}=0.8 \text{ W/(mK)}$	T _s = 25 °C	52	Α	
	T _j = 175 °C	T _s = 70 °C	43	A	
lc	λ_{paste} =2.5 W/(mK)	T _s = 25 °C	58	Α	
	T _j = 175 °C	T _s = 70 °C	48	Α	
I _{Cnom}			35	Α	
I _{CRM}	$I_{CRM} = 3 \times I_{Cnom}$		105	А	
V _{GES}			-20 20	V	
t _{psc}	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T _j = 150 °C	10	μs	
Tj			-40 175	°C	
Diode 1 ·	- 6			•	
V _{RRM}	T _j = 25 °C		1200		
I _F	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	32	Α	
	T _j = 175 °C	T _s = 70 °C	26	Α	
l _F	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	35	Α	
	T _j = 175 °C	T _s = 70 °C	28	Α	
I _{Fnom}			25	Α	
I _{FRM}	I _{FRM} = 3xI _{Fnom}		75	Α	
I _{FSM}	10 ms, sin 180°, T _i = 150 °C		100	Α	
Tj			-40 175		
Diode 7 ·	- 12			•	
V _{RRM}	T _j = 25 °C		1200	V	
l _F	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	44	Α	
	T _j = 175 °C	T _s = 70 °C	35	Α	
I _F	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	49	Α	
	T _j = 175 °C	T _s = 70 °C	40	Α	
I _{Fnom}			35	Α	
I _{FRM}	I _{FRM} = 3 x I _{Fnom}		105	Α	
I _{FSM}	10 ms, sin 180°, T _j = 150 °C		170	A	
Tj			-40 175 °C		
Module		I			
I _{t(RMS)}	20 A per spring		40	А	
T _{stg}			-40 125	°C	
Visol	AC sinus 50 Hz, 1 r	min	2500		



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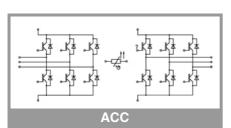
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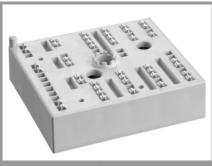
• 4Q inverters

Remarks

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- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage V_{DC}≤800V
- Temperature sensor: no basic insulation to main circuit, signal processing with reference to –DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information



Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
IGBT 1 -	6					
V _{CE(sat)}	I _C = 25 A	T _j = 25 °C		1.85	2.10	V
	V _{GE} = 15 V chiplevel	T _i = 150 °C		2.25	2.45	V
V _{CE0}	chipievei	T _i = 25 °C		0.80	0.90	v
* CEU	chiplevel	$T_i = 150 \text{ °C}$		0.70	0.80	v
r _{CE}	V _{GE} = 15 V	$T_i = 25 \text{ °C}$		42	48	mΩ
·CE	chiplevel	$T_i = 150 ^{\circ}C$		62	66	mΩ
V _{GE(th)}	$V_{GE} = V_{CE} V, I_{C} = 1$		5	5.8	6.5	V
	$V_{GE} = 0 V$	T _i = 25 °C		0.1	0.3	mA
	V _{CE} = 1200 V	,				mA
Cies		f = 1 MHz		1.43		nF
C _{oes}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		0.12		nF
C _{res}	$V_{GE} = 0 V$	f = 1 MHz		0.09		nF
Q _G	V _{GE} = - 8 V+ 15 V			142		nC
R _{Gint}	T _j = 25 °C			0.0		Ω
t _{d(on)}	V _{CC} = 600 V	T _j = 150 °C		96		ns
tr	$I_{\rm C} = 25 {\rm A}$	T _j = 150 °C		80		ns
Eon	$R_{G on} = 39 \Omega$ $R_{G off} = 39 \Omega$	T _j = 150 °C		4.2		mJ
t _{d(off)}	di/dt _{on} = 250 A/µs	T _j = 150 °C		400		ns
t _f	di/dt _{off} = 400 A/µs	T _j = 150 °C		51		ns
	du/dt = 3600 V/µs					
E _{off}	V _{GE} = +15/-15 V L _s = 22 nH	T _j = 150 °C		2.6		mJ
R _{th(j-s)}	per IGBT, $\lambda_{paste}=0.8$	 8 W/(mK)		1		K/W
R _{th(j-s)}	per IGBT, $\lambda_{\text{paste}}=2.1$			0.84		K/W
IGBT 7 -				0.01		
V _{CE(sat)}	I _C = 35 A	T _i = 25 °C		1.85	2.10	V
CE(sat)	V _{GE} = 15 V	-				-
	chiplevel	T _j = 150 °C		2.25	2.45	V
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V
		T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V	T _j = 25 °C		30	34	mΩ
	chiplevel	T _j = 150 °C		44	47	mΩ
V _{GE(th)}	$V_{GE} = V_{CE} V, I_C = 1$		5	5.8	6.5	V
ICES	$V_{GE} = 0 V$	T _j = 25 °C		0.1	0.3	mA
	V _{CE} = 1200 V			-		mA
Cies	V _{CE} = 25 V	f = 1 MHz		1.95		nF
Coes	$V_{GE} = 20$ V	f = 1 MHz		0.16		nF
C _{res}		f = 1 MHz	_	0.12		nF
Q _G	V _{GE} = - 8 V+ 15 V	1		200		nC
R _{Gint}	$T_j = 25 \ ^{\circ}C$	I		0		Ω
t _{d(on)}	$V_{CC} = 600 V$ $I_{C} = 35 A$	T _j = 150 °C		52		ns
t _r	$R_{G on} = 16 \Omega$	T _j = 150 °C		34		ns
Eon	$R_{G off} = 16 \Omega$	T _j = 150 °C		3.9		mJ
t _{d(off)}	di/dt _{on} = 680 A/µs	T _j = 150 °C	_	337		ns
t _f	$di/dt_{off} = 560 \text{ A/}\mu\text{s}$	T _j = 150 °C	_	53		ns
 F "	du/dt = 4000 V/μs V _{GE} = +15/-15 V	T _i = 150 °C		3.5		mJ
E _{off}	$L_{s} = 22 \text{ nH}$	1,1 - 130 0		5.5		iiiJ
R _{th(j-s)}	per IGBT, $\lambda_{\text{paste}}=0.8 \text{ W/(mK)}$			0.85		K/W
			0.7		K/W	



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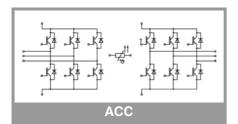
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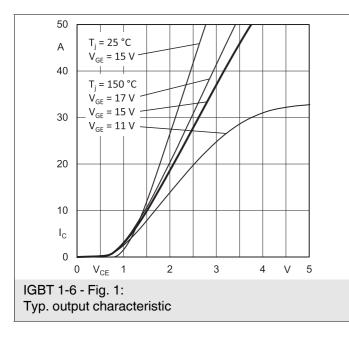
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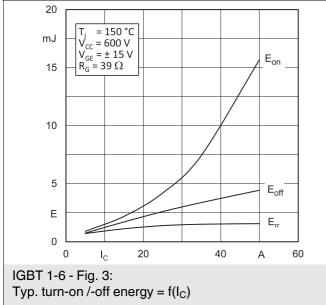
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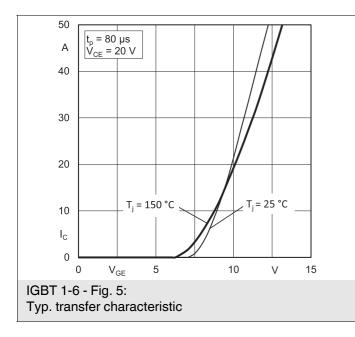
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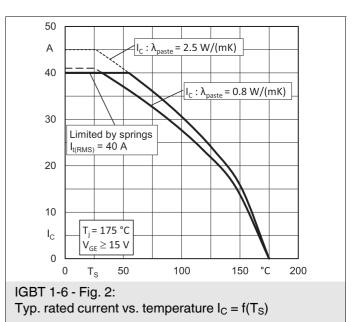
Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Diode 1 -	6					
$V_F = V_{EC}$	I _F = 25 A	T _j = 25 °C		2.41	2.74	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.45	2.79	V
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V
		T _j = 150 °C		0.90	1.10	V
r _F	chiplevel	T _j = 25 °C		44	50	mΩ
		T _j = 150 °C		62	68	mΩ
I _{RRM}	I _F = 25 A di/dt _{off} = 380 A/μs V _{GE} = -15 V	T _j = 150 °C		17		Α
Q _{rr}		T _j = 150 °C		4		μC
E _{rr}	$V_{CC} = 600 V$	T _j = 150 °C		1.4		mJ
R _{th(j-s)}	per Diode, $\lambda_{paste}=0$.8 W/(mK)		1.52		K/W
R _{th(j-s)}	per Diode, λ _{paste} =2.5 W/(mK)			1.31		K/W
Diode 7 -	12					
$V_{F} = V_{EC}$	I _F = 35 A	T _j = 25 °C		2.30	2.62	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.29	2.62	V
V _{F0}	- chiplevel	T _j = 25 °C		1.30	1.50	V
		T _j = 150 °C		0.90	1.10	V
r _F	chiplevel	T _j = 25 °C		29	32	mΩ
		T _j = 150 °C		40	43	mΩ
I _{RRM}	I _F = 35 A di/dt _{off} = 720 A/μs V _{GF} = -15 V	T _j = 150 °C		28		Α
Q _{rr}		T _j = 150 °C		5.8		μC
E _{rr}	$V_{CC} = 600 V$	T _j = 150 °C		2.3		mJ
R _{th(j-s)}	per Diode, λ _{paste} =0.8 W/(mK)			1.2		K/W
R _{th(j-s)}	per Diode, λ_{paste} =2.5 W/(mK)			1		K/W
Module						
L _{CE}				30		nH
Ms	to heat sink		2		2.5	Nm
w				55		g
Temperat	ture Sensor					
R ₁₀₀	T _r =100°C (R ₂₅ =1000Ω)			1670 ± 3%		Ω
R(T)	R(T)=1000Ω[1+A(⁻], A = 7.635*10 ⁻³ °C B = 1.731*10 ⁻⁵ °C ⁻²					

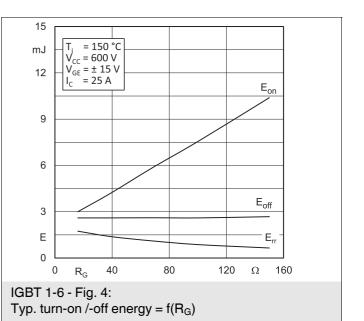


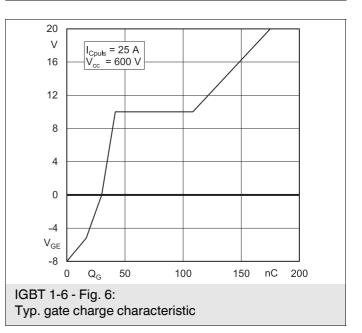




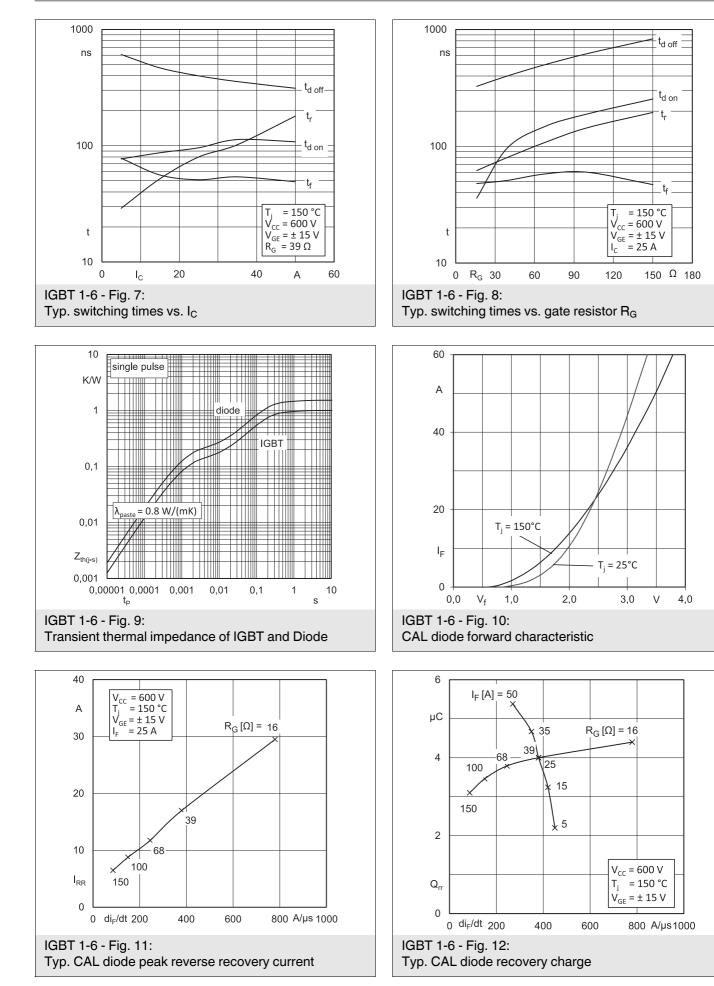


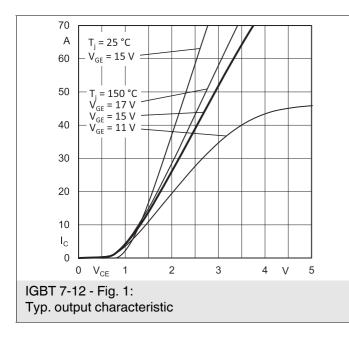


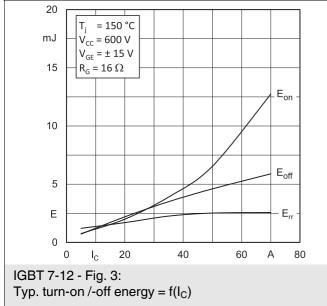


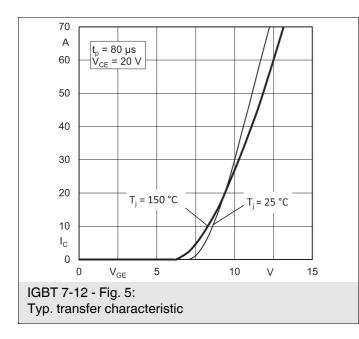


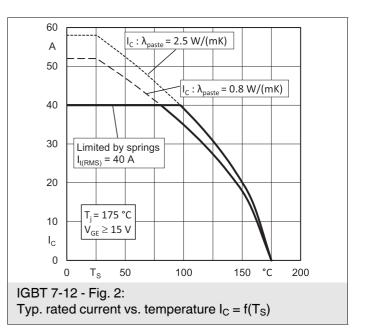
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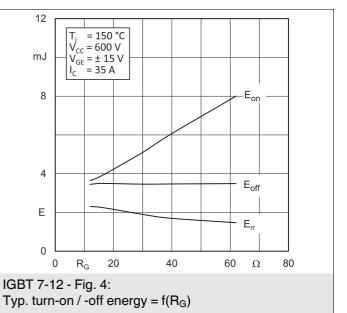


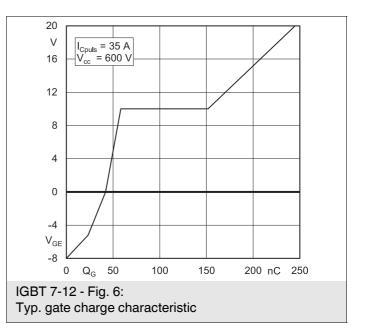




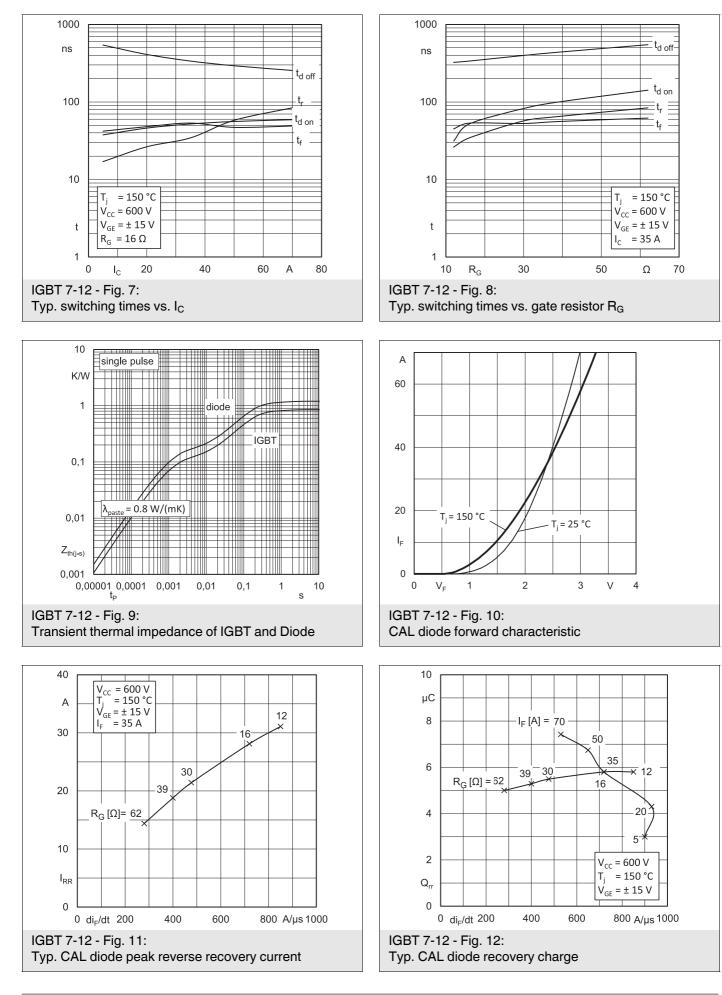


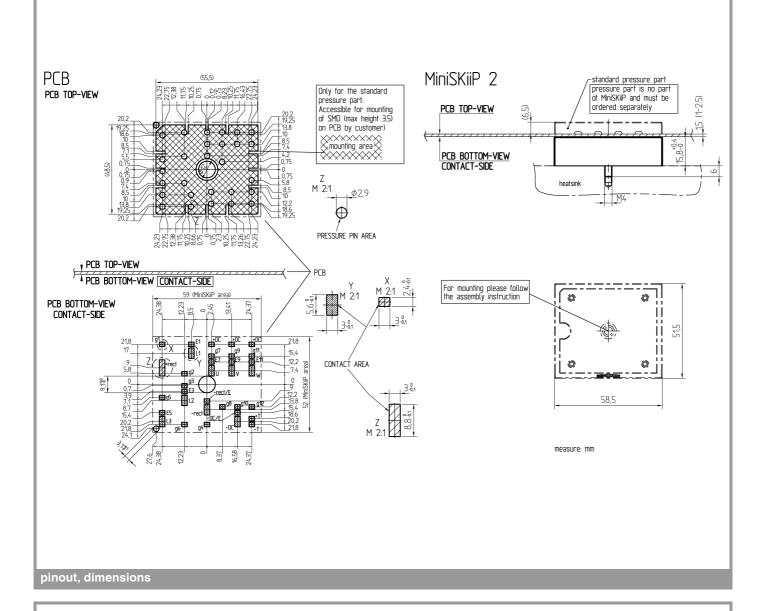


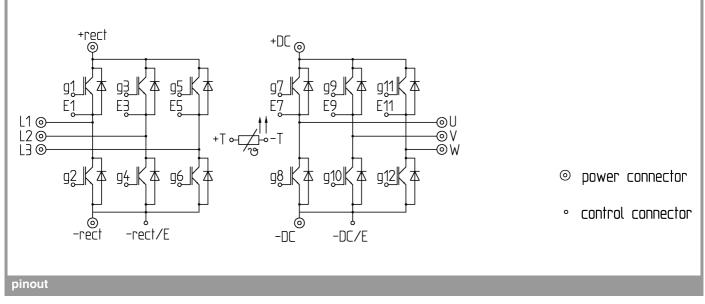




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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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